

SM12GZ47, SM12JZ47, SM12GZ47A, SM12JZ47A

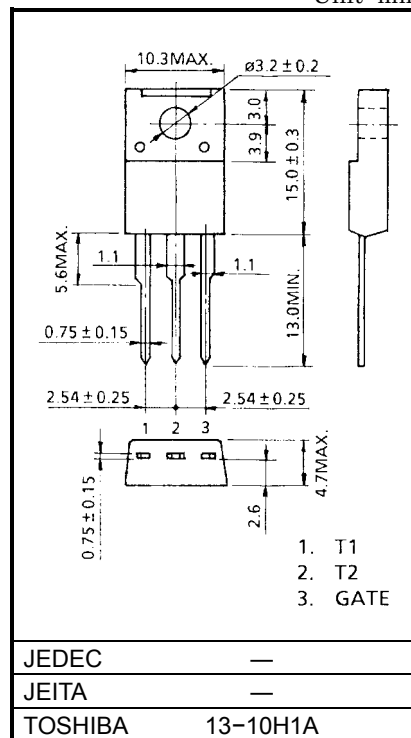
AC POWER CONTROL APPLICATIONS

- Repetitive Peak off-State Voltage : $V_{DRM} = 400, 600V$
- R.M.S On-State Current : $I_T (RMS) = 12A$
- High Commutating (dv / dt)
- Isolation Voltage : $V_{Isol} = 1500V AC$

MAXIMUM RATINGS

CHARACTERISTIC	SYMBOL	RATING	UNIT
Repetitive Peak Off-State Voltage and Repetitive Peak Reverse Voltage	SM12GZ47 SM12GZ47A SM12JZ47 SM12JZ47A	V_{DRM}	V
R. M. S. On-state Current (Full Sine Waveform TC = 72°C)	$I_T (RMS)$	12	A
Peak One Cycle Surge On-State Current (Non-Repetitive)	I_{TSM}	120 (50Hz)	A
		132 (60Hz)	
I^2t Limit Value	I^2t	72	A ² s
Critical Rate of Rise of On-State Current (Note 1)	di / dt	50	A / μs
Peak Gate Power Dissipation	P_{GM}	5	W
Average Gate Power Dissipation	$P_G (AV)$	0.5	W
Peak Gate Voltage	V_{FGM}	10	V
Peak Gate Current	I_{GM}	2	A
Junction Temperature	T_j	-40~125	°C
Storage Temperature Range	T_{stg}	-40~125	°C
Isolation Voltage (AC, t = 1min.)	V_{Isol}	1500	V

Unit: mm



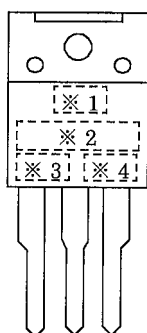
Weight: 1.7g

 Note 1: di / dt test condition

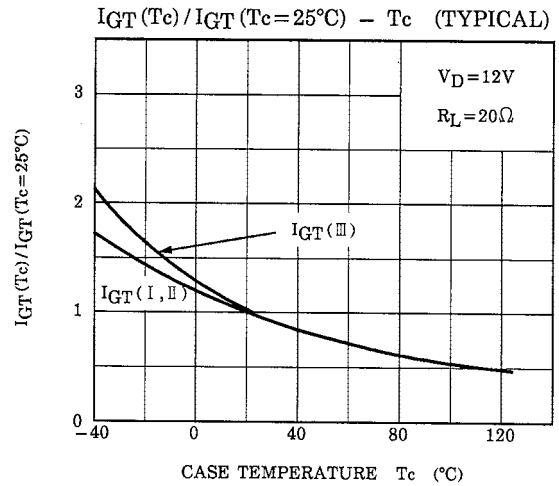
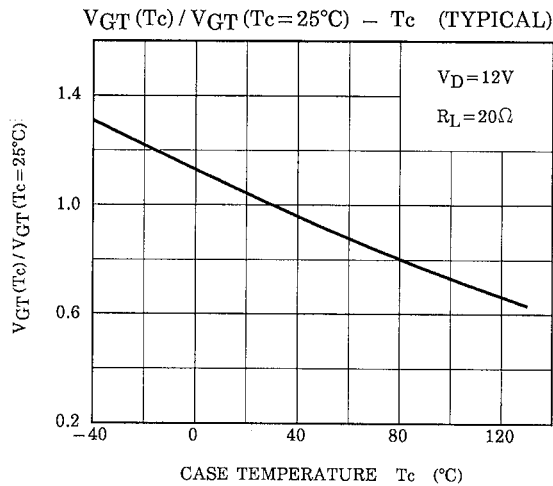
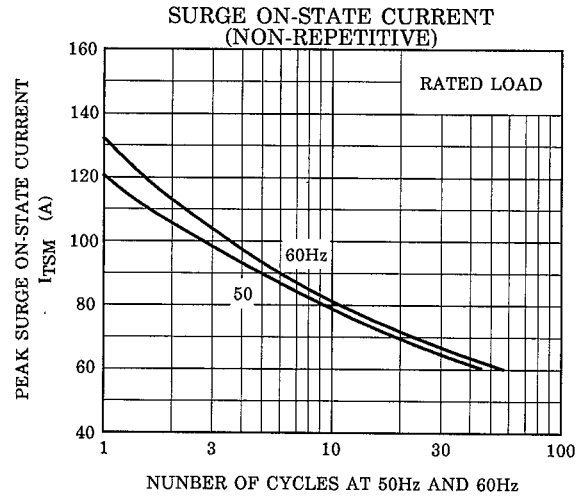
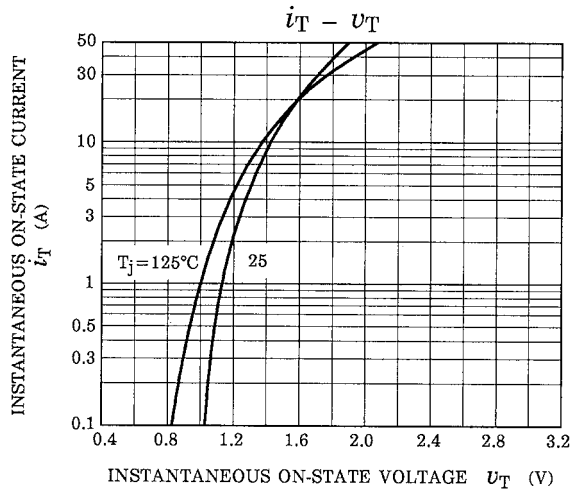
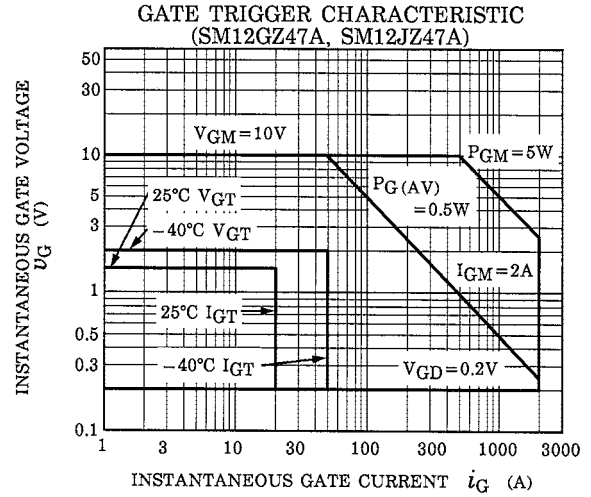
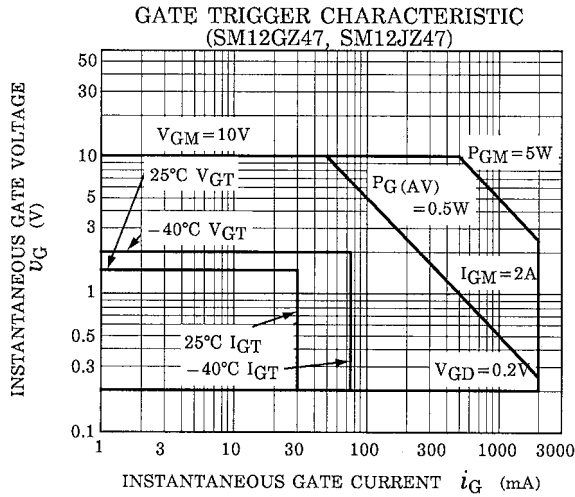
 $V_{DRM} = 0.5 \times \text{Rated}$
 $I_{TM} \leq 17A$
 $t_{gw} \geq 10\mu s$
 $t_{gr} \leq 250ns$
 $i_{gp} = I_{GT} \times 2.0$

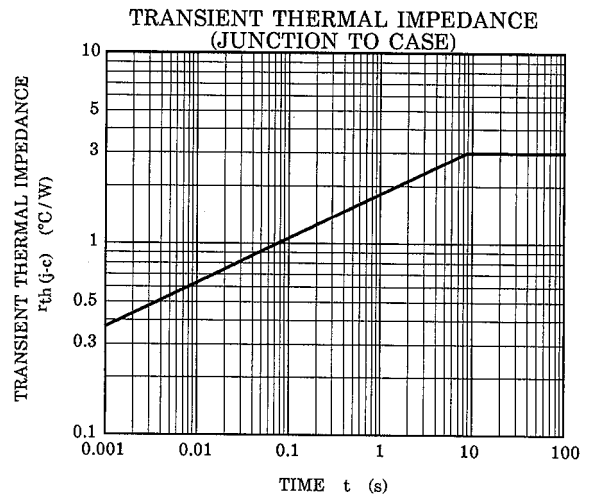
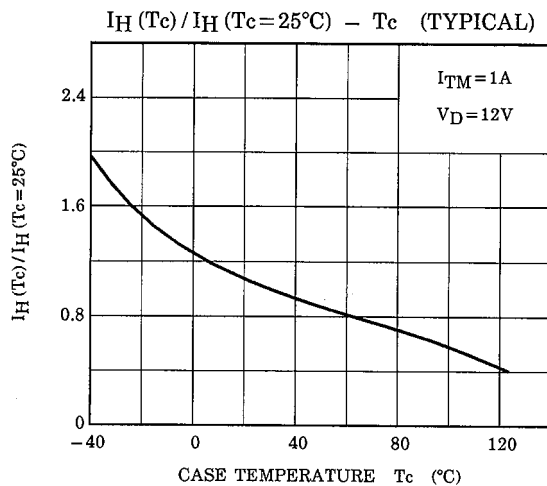
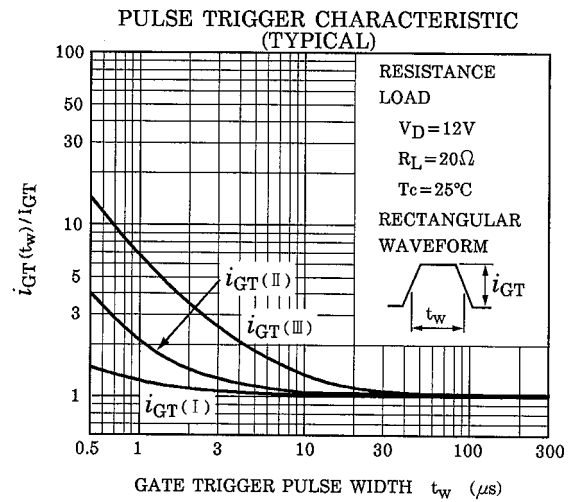
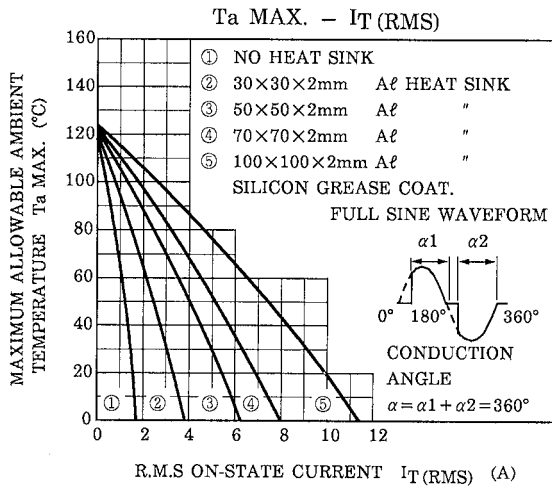
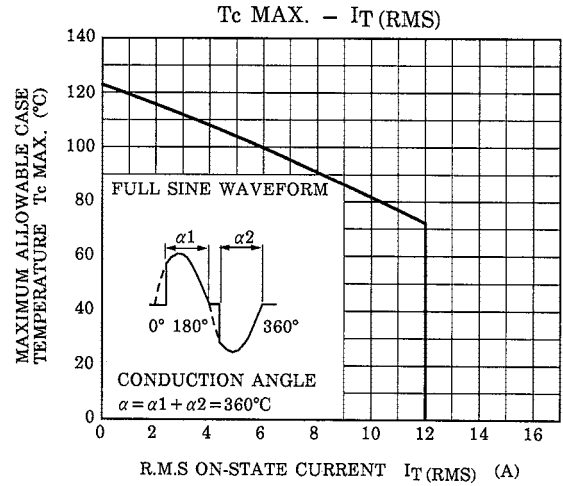
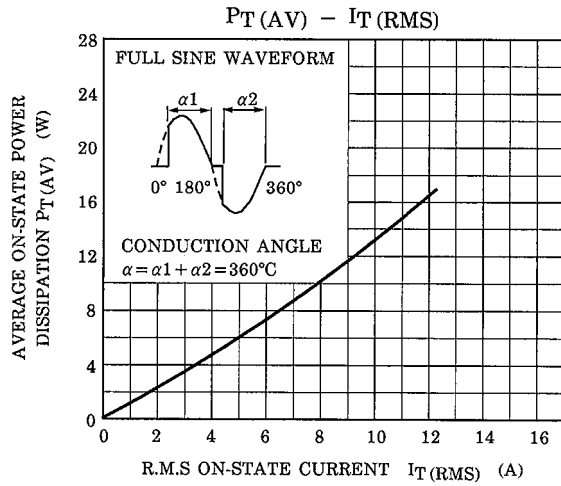
ELECTRICAL CHARACTERISTICS (Ta = 25°C)

CHARACTERISTIC		SYMBOL	TEST CONDITION		MIN	TYP.	MAX	UNIT	
Repetitive Peak Off-State Current		I _{DRM}	V _{DRM} = Rated		—	—	20	μA	
Gate Trigger Voltage		I	V _{GT}	V _D = 12V, R _L = 20Ω	T2 (+) , Gate (+)	—	—	1.5	V
		II			T2 (+) , Gate (–)	—	—	1.5	
		III			T2 (–) , Gate (–)	—	—	1.5	
		IV			T2 (–) , Gate (+)	—	—	—	
Gate Trigger Current	SM12GZ47 SM12JZ47	I	I _{GT}	V _D = 12V, R _L = 20Ω	T2 (+) , Gate (+)	—	—	30	mA
		II			T2 (+) , Gate (–)	—	—	30	
		III			T2 (–) , Gate (–)	—	—	30	
		IV			T2 (–) , Gate (+)	—	—	—	
	SM12GZ47A SM12JZ47A	I			T2 (+) , Gate (+)	—	—	20	
		II			T2 (+) , Gate (–)	—	—	20	
		III			T2 (–) , Gate (–)	—	—	20	
		IV			T2 (–) , Gate (+)	—	—	—	
Peak On-State Voltage		V _{TM}	I _{TM} = 17A		—	—	1.5	V	
Gate Non-Trigger Voltage		V _{GD}	V _D = Rated, T _c = 125°C		0.2	—	—	V	
Holding Current		I _H	V _D = 12V, I _{TM} = 1A		—	—	50	mA	
Thermal Resistance		R _{th} (j-c)	Junction to Case, AC		—	—	3.0	°C / W	
Critical Rate of Rise of Off-State Voltage	SM12GZ47 SM12JZ47	dv / dt	V _{DRM} = Rated, T _j = 125°C Exponential Rise		—	300	—	V / μs	
	SM12GZ47A SM12JZ47A				—	200	—		
Critical Rate of Rise of Off-State Voltage at Commutation	SM12GZ47 SM12JZ47	(dv / dt) c	V _{DRM} = 400V, T _j = 125°C (di / dt) c = – 6.5A / ms		10	—	—	V / μs	
	SM12GZ47A SM12JZ47A				4	—	—		

MARKING


*NUMBER	SYMBOL		MARK
*1	TOSHIBA PRODUCT MARK		
*2	TYPE	SM12GZ47, SM12GZ47A	M12GZ47
		SM12JZ47, SM12JZ47A	M12JZ47
*3	SM12GZ47A, SM12JZ47A		A
*4	Lot Number Month (Starting from Alphabet A) Year (Last Decimal Digit of the Current Year)		Example 8A: January 1998 8B: February 1998 8L: December 1998





RESTRICTIONS ON PRODUCT USE

000707EAA

- TOSHIBA is continually working to improve the quality and reliability of its products. Nevertheless, semiconductor devices in general can malfunction or fail due to their inherent electrical sensitivity and vulnerability to physical stress. It is the responsibility of the buyer, when utilizing TOSHIBA products, to comply with the standards of safety in making a safe design for the entire system, and to avoid situations in which a malfunction or failure of such TOSHIBA products could cause loss of human life, bodily injury or damage to property.
In developing your designs, please ensure that TOSHIBA products are used within specified operating ranges as set forth in the most recent TOSHIBA products specifications. Also, please keep in mind the precautions and conditions set forth in the "Handling Guide for Semiconductor Devices," or "TOSHIBA Semiconductor Reliability Handbook" etc..
- The TOSHIBA products listed in this document are intended for usage in general electronics applications (computer, personal equipment, office equipment, measuring equipment, industrial robotics, domestic appliances, etc.). These TOSHIBA products are neither intended nor warranted for usage in equipment that requires extraordinarily high quality and/or reliability or a malfunction or failure of which may cause loss of human life or bodily injury ("Unintended Usage"). Unintended Usage include atomic energy control instruments, airplane or spaceship instruments, transportation instruments, traffic signal instruments, combustion control instruments, medical instruments, all types of safety devices, etc.. Unintended Usage of TOSHIBA products listed in this document shall be made at the customer's own risk.
- The information contained herein is presented only as a guide for the applications of our products. No responsibility is assumed by TOSHIBA CORPORATION for any infringements of intellectual property or other rights of the third parties which may result from its use. No license is granted by implication or otherwise under any intellectual property or other rights of TOSHIBA CORPORATION or others.
- The information contained herein is subject to change without notice.